DESCRIPTION

These high-voltage, high-current Darlington transistor arrays are comprised of seven silicon NPN Darlington pairs on a common monolithic substrate. All units feature open collector outputs and integral suppression diodes for inductive loads. Peak inrush currents to 600mA are allowable, making them ideal for driving tungsten filament lamps also.

The Type ULN2003 has a series base resistor to each Darlington pair, and thus allows operation directly with TTL or CMOS 5V supply voltage.

The Type ULN2004 has an appropriate series input resistor to allow its operation directly from CMOS or PMOS outputs utilizing supply voltages of 6 to 15V. The required input current is below that of the Type ULN2003.

In all cases, the individual Darlington pair collector current rating is 500mA. However, outputs may be paralleled for higher load current capability. All devices are supplied in a 15-pin dual in-line plastic package.



TYPE ULN2003 (each driver)



PIN CONFIGURATION



FEATURES

- Peak inrush current 600mA
- Protected internally against inductive loads
- Open collector topology
- Compatible with most logic technologies

ABSOLUTE MAXIMUM RATINGS

at 25°C Free-Air temperature for any one Darlington pair unless otherwise specified.

PARAMETER		RATING	UNIT	
VCE	Output voltage	50	v	
Vin	Input voltage	30	v	
VEBO	Emitter base voltage	6	v	
Ic	Continuous collector current	500	mA	
lB	Continuous base current	25	mA	
PD	Power dissipation	1.3	w	
	Derating factor above 25°C	95	°C/W	
TA	Ambient temperature range (operating)	0 to +85	°C	
Ts	Storage temperature range	-65 to +150	°C	

NOTE

Under normal operating conditions, these units will sustain 350mA per output with $V_{CE(SAT)} \approx 1.6V$ at 70°C with a pulse width of 20 ms and a duty cycle of 30%.

DC ELECTRICAL CHARACTERISTICS $T_A = 25^{\circ}$ C unless otherwise specified. 1.2.3

	PARAMETER	TEST CONDITIONS	Test Fig.	LIMITS			
				Min	Тур	Max	UNIT
ICEX	Output leakage current Type ULN2004	V _{CE} = 50V, T _A = 70°C V _{CE} = 50V, T _A = 70°C, V _{IN} = 1V	1A 1B	-	-	100 500	μА μА
VCE(SAT)	Collector-emitter Saturation voltage	I _C = 350mA, I _B = 500μA I _C = 200mA, I _B = 350μA I _C = 100mA, I _B = 250μA	2 2 2		1.25 1.1 0.9	1.6 1.3 1.1	V V V
lin(on)	Input current Type ULN2003 Type ULN2004	V _{IN} = 3.85V V _{IN} = 5V V _{IN} = 12V	3 3 3	111	0.93 0.35 1.0	1.35 0.5 1.45	mA mA mA
IN(OFF)	Input current	$I_{\rm C} = 500\mu {\rm A}, \ T_{\rm A} = 70^{\circ}{\rm C}$	4	50	65	-	μA
Vin(ON)	Input voltage						ł
	Type ULN2003	V _{CE} = 2V, I _C = 200mA V _{CE} = 2V, I _C = 250mA V _{CE} = 2V, I _C = 300mA	5 5 5		-	2.4 2.7 3.0	
	Type ULN2004	V _{CE} = 2V, I _C = 125mA V _{CE} = 2V, I _C = 200mA V _{CE} = 2V, I _C = 275mA V _{CE} = 2V, I _C = 350mA	5 5 5 5 5	- - -		5.0 6.0 7.0 8.0	V V V V
CIN	Input capacitance		-	- 1	15	30	pF
IR	Clamp diode leakage current	V _R = 50V	6	-	-	50	μA
VF	Clamp diode forward voltage	I _F = 350mA	7	-	1.7	2	V

NOTES

1. All limits stated apply to the complete Darlington series except as specified for a single device type.

2. The IN(OFF) current limit guarantees against partial turn-on of the output

3. The VIN(ON) voltage limit guarantees a minimum output sink current per the specified

test conditions

AC ELECTRICAL CHARACTERISTICS T_A = 25°C unless otherwise specified.^{1,2,3}

PARAMETER	TEST CONDITIONS	Test Fig.	LIMITS			UNIT
FARAMETER			Min	Тур	Max	
tPLH Turn-on delay	0.5 EIN to 0.5 EOUT		-	1.0	5	μS
tPHL Turn-off delay	0.5 EIN to 0.5 EOUT	-		1.0	5	μS

NOTES

1. All limits stated apply to the complete Darlington series except as specified for a single device type.

2. The IIN(OFF) current limit guarantees against partial turn-on of the output.

 The ViN(ON) voltage limit guarantees a minimum output sink current per the specified test conditions

ULN2003/04





TEST FIGURES



Signetics

Figure 7

TEST FIGURES (Cont'd)



TYPICAL APPLICATIONS



Figure 6

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